To all our customers

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Renesas Technology Corp.
Customer Support Dept.
April 1, 2003

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HVD141

Silicon Epitaxial Trench Pin Diode for Antenna Switching

ADE-208-1087 (Z)

Rev. 0
Jan. 2001

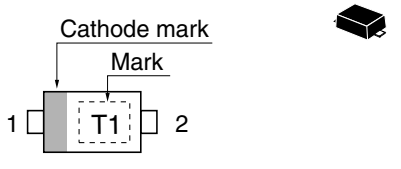
Features

- Low capacitance. (C = 0.82 pF max)
- Low forward resistance. (rf = 0.8 Ω max)
- Super small Flat Package (SFP) is suitable for surface mount design.

Ordering Information

Type No.	Laser Mark	Package Code
HVD141	T1	SFP

Pin Arrangement



1. Cathode
2. Anode

Absolute Maximum Ratings

(Ta = 25°C)

Item	Symbol	Value	Unit
Reverse voltage	V_R	30	V
Forward current	I_F	100	mA
Power dissipation	Pd	150	mW
Junction temperature	Tj	125	°C
Storage temperature	Tstg	–55 to +125	°C

Electrical Characteristics

(Ta = 25°C)

Item	Symbol	Min	Typ	Max	Unit	Test Condition
Reverse current	I_R	—	—	0.1	μA	V_R = 30 V
Forward voltage	V_F	—	—	1.0	V	I_F = 10 mA
Capacitance	C	—	—	0.82	pF	V_R = 1 V, f = 1 MHz
Forward resistance	r_f	—	—	0.8	Ω	I_F = 10 mA, f = 100 MHz

Note: Please do not use the soldering iron due to avoid high stress to the SFP package.

Main Characteristic

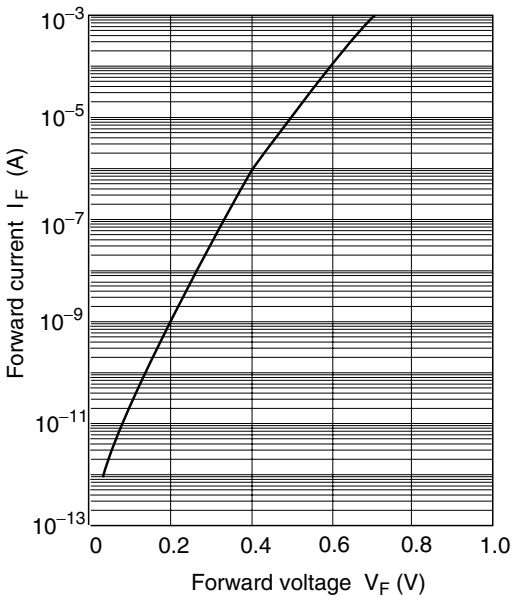


Fig.1 Forward current Vs. Forward voltage

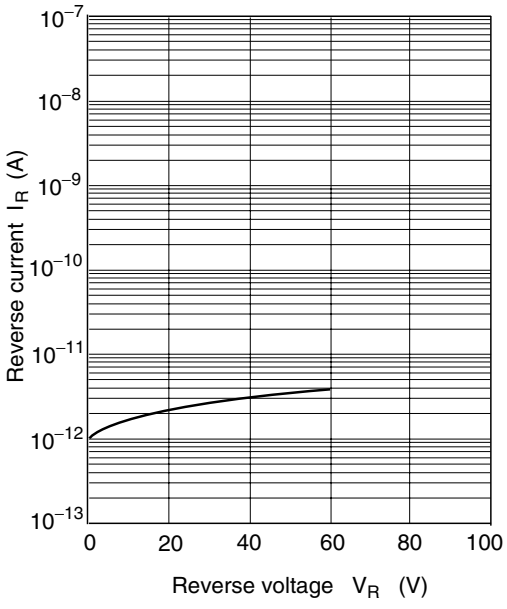


Fig.2 Reverse current Vs. Reverse voltage

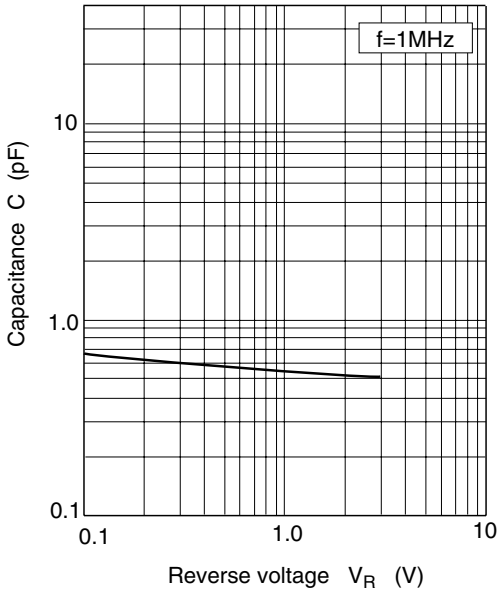


Fig.3 Capacitance Vs. Reverse voltage

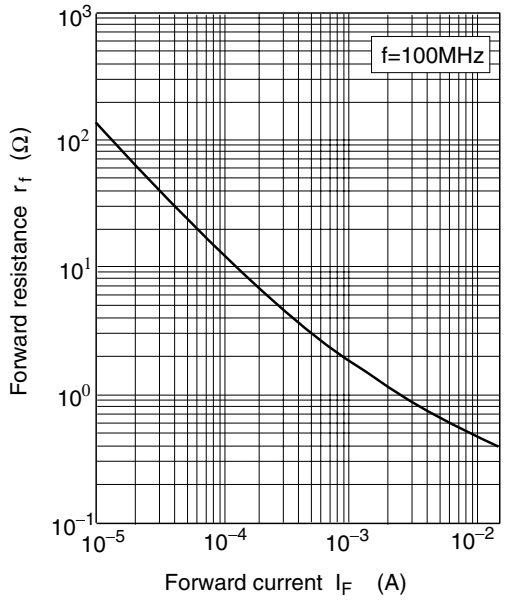


Fig.4 Forward resistance Vs. Forward current

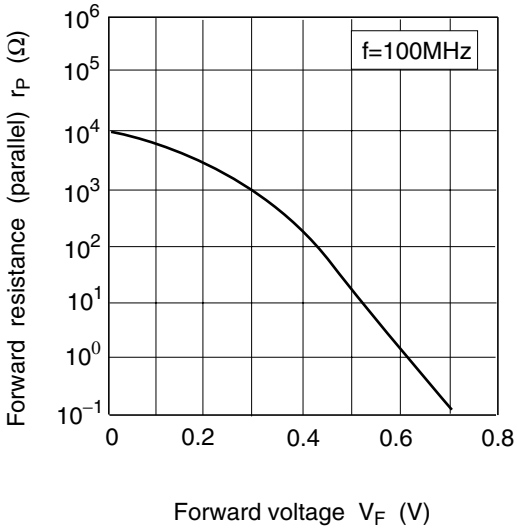
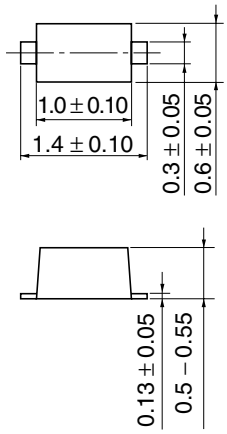


Fig.5 Forward resistance (parallel) Vs. Forward voltage

Package Dimensions

Unit: mm



Hitachi Code	SFP
JEDEC	—
EIAJ	—
Mass (reference value)	0.0010 g

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